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Helium Behavior in Vanadium-Based Alloys Irradiated in the Dynamic Helium Charging Experiments

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Helium effect of neutron irradiated vanadium alloys, containing titanium, has been studied using Dynamic Helium Charging Experiment (DHCE) in FFTF. Cavity formation was observed only in pure vanadium irradiated at 430 to 600°C and in V-5Ti irradiated at 600°C. No apparent cavity formation was obtained in V-3Ti-1Si and V-4Cr-4Ti. The precipitation of titanium oxide in V-5Ti, V-3Ti-1Si and V-4Cr-4Ti occurred in all irradiation conditions in this study and the precipitates of Ti$_2$Si$_3$ only appeared in V-3Ti-1Si irradiated at 600°C up to 15 dpa with helium generation rate of 4 appmHe/dpa. It is suggested that titanium oxide plays an important role for suppression of cavity formation and swelling from early stage of irradiation. Detailed characterization of precipitates and He effect for neutron damages in vanadium alloys are discussed here.

Introduction

Extensive research of low activation vanadium-base alloys for application in fusion reactor first wall and blanket structure has been conducted in the last decade because of the excellent combination of mechanical and physical properties before and after irradiation. One unresolved issue in the performance of these alloys, however, remains, i.e., the effect of simultaneous helium and neutron damage in fusion relevant irradiation condition (at a ratio of 4–5 appm helium/displacement per atom [dpa]) on void swelling. Some techniques tritium-trick\textsuperscript{[1]}, cyclotron-injection\textsuperscript{[2]}, and boron-doping\textsuperscript{[3]} have been used to simulate the helium generation rate in fusion relevant condition. However the amount of helium was not consistent with pre-assumption and helium aggregated as helium bubbles on or near grain boundaries before neutron irradiation\textsuperscript{[4]}.

In the Dynamic Helium Charging Experiments, DHCE, the fusion–relevant helium–to–dpa ratio is simulated realistically by utilizing the transmutation of controlled amounts of $^6$Li and a predetermined amount of tritium–doped mother alloy immersed in $^6$Li + Li\textsuperscript{[5]}.

This report describes the results of microstructural characterization of vanadium alloy specimens irradiated in FFTF with the DHCE technique.

Experimental Procedure

The elemental composition of the vanadium alloys (pure V, V-5Ti, V-3Ti-1Si and V-4Cr-4Ti as ANL designation BL-19, 45, 46 and 47, respectively) is listed in Table 1. Fabrication procedures of alloy ingots as well as annealed plates and sheets have been reported in previous works\textsuperscript{[6]}. TEM disks punched from 0.3mm-thick cold-worked sheets, were annealed at 1050°C. The only secondary phase present in the as-annealed specimens was Ti(O, N, C), which is normally observed in titanium-containing vanadium alloys. The alloy specimens were irradiated in the Fast Flux Test Facility (FFTF), at 420, 520 and 600°C to neutron fluence (E>0.1MeV) ranging from 0.37 to 6.4 x 10\textsuperscript{23} n/m\textsuperscript{2}, 15 to 27 displacement per atom (dpa) estimated for pure vanadium. Helium in the alloy specimens was generated the decay of tritium transferred from the mother alloy via liquid lithium. Table 2 summarizes the actual damage and helium contents determined from tensile and TEM specimens. Helium and tritium were determined by mass spectroscopy at Rockwell International Inc., Canoga Park, CA.

Table 1: The chemical composition of vanadium alloys in this work.

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<tr>
<th>Nominal Composition (wt. %)</th>
<th>Impurity Composition (ppm)</th>
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<tr>
<td></td>
<td>O</td>
</tr>
<tr>
<td>V</td>
<td>1101</td>
</tr>
<tr>
<td>V-2.5Ti-0.9Si</td>
<td>345</td>
</tr>
<tr>
<td>V-4.6Ti</td>
<td>300</td>
</tr>
<tr>
<td>V-4.1Cr-4.3Ti</td>
<td>350</td>
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Table 2: Summary of irradiation parameters of Dynamic Helium Charging Experiment and helium contents measured in V-4Cr-4Ti specimens. See in ref\textsuperscript{[6]}

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<th>Irradiation Temp. (°C)</th>
<th>Total Damage for pure V (dpa)</th>
<th>Helium Content (ppm/dpa)</th>
<th>Actual He/dpa Ratio (ppm/dpa)</th>
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<tr>
<td>430</td>
<td>27</td>
<td>12.0 ± 0.5</td>
<td>0.39</td>
</tr>
<tr>
<td>430</td>
<td>27</td>
<td>22.5 ± 0.1</td>
<td>0.73</td>
</tr>
<tr>
<td>500</td>
<td>15</td>
<td>14.9 ± 0.1</td>
<td>0.83</td>
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The retrieved TEM specimens were cleaned ultrasonically in alcohol prior to microstructural analysis. The examined TEM disks were not degassed. The irradiated specimens were jet-thinned for TEM observation in a solution of 20% sulfuric acid - 80% methanol maintained at -25°C. TEM observation was performed with JEOL-100CX-II in ANL operating at 100kV.
Results

Pure Vanadium

Figure 1 shows the microstructure of neutron irradiated pure vanadium with DHCE method from 430 to 600°C with fluences from 15 to 28 dpa. Figure 1(a) shows a number of fine cavities in the matrix of the pure V specimen irradiated at 430°C and Fig. 1(d) shows larger ones irradiated at 600°C. However, at 500°C, no cavity was seen in the matrix of pure vanadium. On the other hand, dense and very fine dislocation loops or precipitates were formed in the matrix irradiated at 430°C and a low density of large dislocation loops are also observed. Above 500°C, precipitates (mean size of their major axis is about 5 nm) appeared and grew up with increasing irradiation temperature as shown in Fig. 1(b), (c) and (d). The irradiation-induced precipitates show fringes. Stacking fault energy in bcc structure is generally too high to form stacking fault with appreciable width. Figure 2 shows the dislocation images and diffraction pattern obtained from the same area. In Fig. 2(a), three types of platelet precipitates exist with edge-on configuration. The foil normal of vanadium matrix is [111] so that the normal of platelets is type of [112] direction from the analysis of the orientation relationship. Other platelets which are inclined from [111] axis also have the indices of their normal, [112] direction. Thus, the habit plane of platelet precipitate is determined to be (112). Figure 2(b) shows the selected area diffraction pattern and corresponding image of precipitates. The diffraction spots from precipitates appear in diffraction pattern. The d-spacing distance of them is 2.26Å and the type of crystal lattice may be of cubic type. In a recent work, the chemical analysis using EDS made clear that the precipitate consists of vanadium and light elements, C, N or O. It is considered that the nature of the precipitate in pure vanadium is vanadium carbide or vanadium oxide from this work.

V-3Ti-1Si

Small addition of silicon to vanadium alloys has been reported to give resistance to swelling under neutron irradiation[9]. Figure 4 shows the microstructure of neutron-irradiated V-3Ti-1Si with DHCE. At 430°C, cavities were formed with extremely low density as shown in Fig. 4(a). Along with cavity formation, high density of fine precipitates was observed as in V-5Ti. With increasing irradiation temperature, cavities disappeared and the growth rate of planar precipitates rapidly increased as shown in Fig. 4: the irradiation temperature (°C) and the helium generation rate (appmHe/dpa) was 500, 0.5(b), 600, 0.5(c) and 600, 4.2(d), respectively. The planar precipitate in Fig. 4(b-d) resemble one of V-5Ti. At 600°C with 4.2 appmHe/dpa, however, different type of precipitates from titanium oxide appeared in the matrix. Figure 5 shows the bright field images and diffraction pattern of the precipitate in V-3Ti-1Si neutron-irradiated at 600°C with 4.2 appmHe/dpa. Two types of precipitates were formed together in the same grain. The left one shows the titanium oxide as mentioned in the V-5Ti section. The right one, disk type precipitates have a diffraction pattern different from titanium oxide. The weak spots in Fig. 5 are from precipitates of which crystal structure has been determined hexagonal type, with the orientation relationship [110]precipitate//(112)precipitate (111)v//(0001)precipitate and the habit plane of [110]. The d-spacing of (1210) and (3630) of the precipitate is 6.62Å and 2.20Å, respectively. The same type of precipitate has already been observed in V-3Ti-1Si irradiated at 600 and 800°C with a damage level of 15 and 17 dpa, respectively using the tritium-trick technique[10]. The nature of the precipitates has been determined to be titanium silicide by a detailed analysis. The precipitate has been reported to be Ti5Si3 which has hexagonal structure[11] with a lattice constant of a0.
is 7.463Å. Although there are some discrepancies still, it is clear that the titanium silicides were formed only in V-3Ti-1Si irradiated at 600°C.

**V-4Cr-4Ti**

V-Cr-Ti alloys are base alloy for candidate materials of fusion reactor structural materials. In the previous work[6,12], V-4Cr-4Ti alloy has shown excellent radiation-resistant properties under neutron irradiation with concurrent helium generation using the DHCE technique. Figure 6(a) to (c) show the microstructure of V-4Cr-4Ti irradiated at 430°C, 500°C and 600°C, respectively. In Fig. 6(b) and (c), the dark field images obtained using precipitate reflection are inserted. In this work, cavity was never observed in the alloy, V-4Cr-4Ti, which is contrasted to the previous report[12] where cavities were observed around grain boundaries[12]. V-4Cr-4Ti had rather higher dislocation density than other alloys studied here. High density of precipitates are also observed and they grew up and the density increased with raising the irradiation temperature. However, the growth of precipitates was so much larger than in V-5Ti and V-3Ti-1Si. The nature of the precipitates is similar with those in V-5Ti and V-3Ti-1Si observed in this study. Thus, it is conducted that the precipitates formed in neutron-irradiated V-4Cr-4Ti are titanium oxide, TiO or TiO₂ (x<0.5).

**Discussion**

The swelling behavior of neutron-irradiated vanadium alloys has been reported by many workers. The precipitation induced by radiation damage plays an important role for the suppression and procession of radiation-induced swelling. In pure vanadium in this work, the cavity formation was seen at 430°C and 600°C, while, no cavity was observed at 500°C. On the other hand, precipitation of vanadium carbide or oxide occurred in all irradiation conditions. From table 1, pure vanadium, ANL designation: BL-19 contains much more impurity, carbon and oxygen than other pure vanadium used in many of the experiments reported so far. It has been reported that the cavity formation occurred at 500 or 520°C and a few dislocations and no precipitation were observed in FFFT or JOYO irradiation[7,13]. The reason why cavity formation were suppressed at 500°C in this study should be due to the precipitation providing effective sinks for point defects. It is considered that high density of precipitates act as neutral sinks to trap the vacancy and interstitials, and the concentration of point defects are reduced leading to the suppression of cavity formation. In order to examine the mechanism of suppression of cavity formation, the information about the sink strength of these precipitates and the migration of point defects is required. At 600°C, the precipitates were also produced but cavity formation was not suppressed. In this case, precipitates were coarsened and the density were decreased.

In vanadium alloys containing titanium, precipitates were formed in all irradiations conditions and cavity formation were only found in V-5Ti irradiated at 430°C. The formation of void nuclei occurred so easily at low temperatures that the cavity formation only appeared at 430°C. The nature of precipitates produced in V-5Ti, V-3Ti-1Si and V-4Cr-4Ti is mainly Ti₅O, titanium oxide. Ti₅O is not produced in unirradiated vanadium alloys and TiO(N, C) with NaCl is only titanium oxide. The radiation induced precipitates, TiO should play a role as an effective sink for point defects and suppress the cavity formation and swelling provided the sink strength is significantly high. In the previous study[9], titanium silicide, Ti₅Si₃ has been reported to be playing an important role for suppression of swelling in V-4Cr-4Ti and other vanadium alloys. However, in this study, only precipitation of Ti₅Si₃ appears in V-3Ti-1Si irradiated at 600°C. Titanium silicide, Ti₅Si₃ only appeared in vanadium alloys containing silicon. It is suggested that titanium oxide playing the major role in void suppression. The addition of titanium to vanadium alloys is more important to suppress radiation-induced swelling than silicon. On the other hand, it has been reported that the cavity formation occurred in V-3Ti-0.25Si, but no cavity was formed in V-3Ti-0.5Si irradiated at 600°C in FFFT. This observation indicated that stage addition to vanadium alloy is important to suppress the swelling. From the result by H.M. Chung[9], it is likely that V-3Ti-1Si has more effective self-healing property against swelling than V-Ti alloys. We consider that titanium oxide is effective for the suppression of cavity formation from the early stage of irradiation. In the subsequent irradiation, Ti₅Si₃ precipitates are nucleated homogeneously and grow up slowly. Titanium oxides are coarsened significantly during irradiation and are longer able to influence the suppression of cavity formation. Therefore self-healing system against swelling in V-3Ti-1Si is caused by two step formation of precipitates, both titanium oxide and silicide under irradiation. We have to discuss further about which element is more effective for swelling suppression in vanadium alloys.

Only TEM observation of DHCE specimens was done in this experiments and the comparison with both DHCE specimens and He free specimens irradiated with neutron was not examined. For another experiment from ANL designation specimens, TEM observation of Japanese binary vanadium alloys has been performed and the comparison between DHCE specimen and He-free irradiated specimen about swelling behavior has been done. Figure 7 shows the swelling of vanadium alloys for each alloys irradiated with DHCE and conventional neutron irradiation. Except for V-5Mo, the radiation induced cavity formation can't be seen in vanadium alloys. Moreover, V-5Ti and V-3Ti-1Si does
not show the swelling with or without concurrent He implantation. Titanium atoms in solution in vanadium alloys work to suppress the cavity formation as trap for vacancies or impurity atoms during He free neutron irradiation. Addition of oversized solute atoms in metals, especially including titanium in vanadium, has been reported to suppress the swelling remarkably. During neutron irradiation with He implantation, only solute titanium atoms work no longer as effective sink for He atoms. In addition to the titanium atoms in solution, the precipitation of titanium oxide should be effective as trapping sites for He atoms and suppresses the cavity formation and reduce the radiation induced swelling.

![Swelling (%) Chart](image)

**Figure 7**: The swelling of vanadium alloys for each alloys irradiated with DHCE and conventional neutron irradiation. These data were obtained by TEM observation of Japanese vanadium alloy specimens with or without DHCE technique.

**Conclusion**

No void appeared in pure V at 500°C irradiation. The high density of vanadium carbide or vanadium oxide appears to act as sink for point defects and prevents the formation of void nuclei. Precipitates of Ti$_2$O were observed in all Ti-containing vanadium alloys, i.e., V-5Ti, V-3Ti and V-4Cr-4Ti. Since Ti$_2$Si was observed only in V-3Ti-1Si at 600°C, while swelling suppression was observed in all conditions, titanium silicide is not considered essential for swelling suppression from the early stage of irradiation. Void swelling of vanadium alloys was not remarkable when irradiated under concurrent helium generation using DHCE. Swelling suppression by titanium in solution, alone may be sufficient in He-free conditions, while under fusion-relevant He generation, He trapping by fine precipitates, e.g. Ti$_2$O, is effective for swelling reduction.

**Acknowledgment**

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**Reference**

Figure 1: The microstructure of neutron irradiated pure vanadium with DHCE method at from 430 to 600 °C with fluences of 15 to 27 dpa. (a) dislocation and void images at 430°C, (b) dislocation images at 500°C, (c) dislocation images at 600°C with He generation rate of 0.5 He appm/dpa and (d) dislocation and void images at 600°C with He generation rate of 4.2 He appm/dpa.

Figure 2: (a) the precipitate image near [111] direction and (b) one near [110] direction. The selected area diffraction patterns are shown at bottom part respectively and white triangles mark the reflection spot from precipitates.
Figure 3: The microstructure V-5Ti irradiated at from 430 to 600 °C with fluences of 15 to 27 dpa using DHCE method. (a) dislocation and void images, and the void image around grain boundary at 430°C, (b) dislocation and void images at 500°C, (c) dislocation and void images at 600°C with He generation rate of 4.2 He appm/dpa.

Figure 4: The microstructure of V-3Ti-1Si at from 430 to 600 °C with damage level of 15 to 27 dpa using DHCE. (a) dislocation and void images at 430°C, (b) dislocation images at 500°C, (c) dislocation image at 600°C with He generation rate of 0.5 He appm/dpa and (d) dislocation image at 600°C with He generation rate of 4.2 He appm/dpa.
Figure 5: The selected area diffraction patterns and the precipitates in V-3Ti-1Si at from 600 °C with He generation rate of 4.2 He appm/dpa. (a) SADP was obtained near [001] direction. Same type of diffraction pattern with V-5Ti in fig.4. The nature of precipitates should be Ti2O. (b) SADP was obtained close to [111] direction. You can see the weak spot occurred from precipitates.

Figure 6: The microstructure of V-4Cr-4Ti at from 430 to 600 °C with damage level of 15 to 27 dpa using DHCE. (a) dislocation image at 430°C, (b) BF dislocation and WBDF precipitate images at 500°C, (c) BF dislocation and WBDF precipitate images at 600°C.